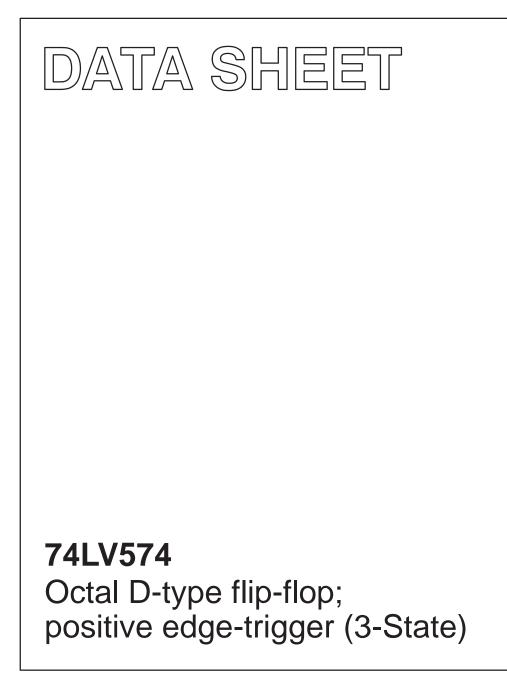
INTEGRATED CIRCUITS



Product specification Supersedes data of 1997 Feb 03 IC24 Data Handbook

1998 Jun 10



Philips Semiconductors



74LV574

FEATURES

- Wide operating voltage: 1.0 to 5.5V
- Optimized for Low Voltage applications: 1.0 to 3.6V
- Accepts TTL input levels between V_{CC} = 2.7V and V_{CC} = 3.6V
- \bullet Typical V_{OLP} (output ground bounce) < 0.8V at V_{CC} = 3.3V, T_{amb} = 25°C
- Typical V_{OHV} (output V_{OH} undershoot) > 2V at V_{CC} = 3.3V, T_{amb} = 25°C
- Common 3-State output enable input
- Output capability: bus driver
- I_{CC} category: MSI

QUICK REFERENCE DATA

DESCRIPTION

The 74LV574 is a low-voltage Si-gate CMOS device and is pin and function compatible with 74HC/HCT574.

The 74LV574 is an octal D-type flip–flop featuring separate D-type inputs for each flip-flop and non-inverting 3-state outputs for bus oriented applications. A clock (CP) and an output enable (\overline{OE}) input are common to all flip-flops.

The eight flip-flops will store the state of their individual D-inputs that meet the set-up and hold times requirements on the LOW-to-HIGH CP transition.

When \overline{OE} is LOW, the contents of the eight flip-flops is available at the outputs. When \overline{OE} is HIGH, the outputs go to the high impedance OFF-state. Operation of the \overline{OE} input does not affect the state of the flip-flops.

GND = 0V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5 \text{ ns}$										
SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT						
t _{PHL} /t _{PLH}	Propagation delay CP to Q _n	$C_L = 15 pF$ $V_{CC} = 3.3V$	13	ns						
f _{max}	Maximum clock frequency	C _L = 15pF, V _{CC} = 3.3V	77	MHz						
Cl	Input capacitance		3.5	pF						
C _{PD}	Power dissipation capacitance per flip-flop	Notes 1 and 2	25	pF						

NOTES:

. C_{PD} is used to determine the dynamic power dissipation (P_D in μ W) P_D = C_{PD} × V_{CC}² x f_i + Σ (C_L × V_{CC}² × f_o) where: f_i = input frequency in MHz; C_L = output load capacity in pF; f_o = output frequency in MHz; V_{CC} = supply voltage in V; Σ (C_L × V_{CC}² × f_o) = sum of the outputs.

2. The condition is $V_I = GND$ to V_{CC}

ORDERING AND PACKAGE INFORMATION

PACKAGES	TEMPERATURE RANGE	NGE OUTSIDE NORTH AMERICA		PKG. DWG. #
20-Pin Plastic DIL	–40°C to +125°C	74LV574 N	74LV574 N	SOT146-1
20-Pin Plastic SO	-40°C to +125°C	74LV574 D	74LV574 D	SOT163-1
20-Pin Plastic SSOP Type II	–40°C to +125°C	74LV574 DB	74LV574 DB	SOT339-1
20-Pin Plastic TSSOP Type I	–40°C to +125°C	74LV574 PW	74LV574PW DH	SOT360-1

PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
1	OE	Output enabled input (active LOW)
2, 3, 4, 5, 6, 7, 8, 9	D0–D7	Data inputs
19, 18, 17, 16, 15, 14, 13, 12	Q0–Q7	3-State flip-flop outputs
10	GND	Ground (0V)
11	СР	Clock input (LOW-to-HIGH, edge-triggered)
20	VCC	Positive supply voltage

FUNCTION TABLE

OPERATING	11	NPUT	S	INTERNAL	OUTPUTS
MODES	OE	СР	Dn	FLIP-FLOPS	Q0 to Q7
Load and read register	L	$\stackrel{\uparrow}{\uparrow}$	l h	L H	L H
Load register and disable outputs	H H	$\stackrel{\uparrow}{\leftarrow}$	l h	L H	Z Z

H = HIGH voltage level

= HIGH voltage level one set-up time prior to the LOW-to-HIGH CP transition

L = LOW voltage level L = LOW voltage level

= LOW voltage level one set-up time prior to the LOW-to-HIGH CP transition

= High impedance OFF-state

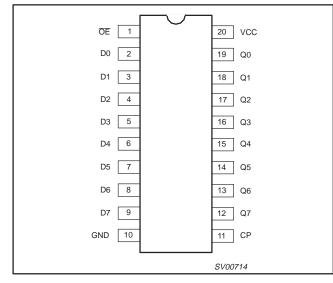
LOW-to-HIGH clock transition

h

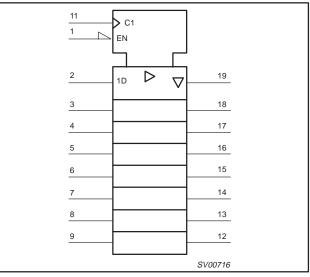
Z ↑

74LV574

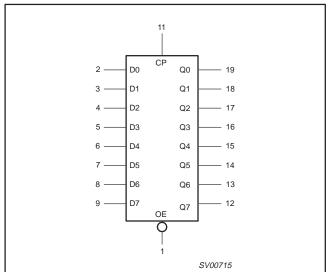
PIN CONFIGURATION



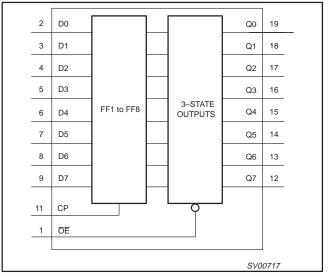
LOGIC SYMBOL (IEEE/IEC)



LOGIC SYMBOL

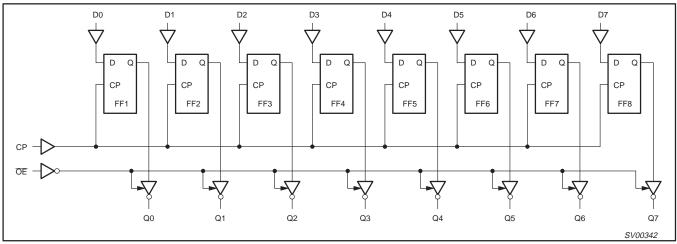


FUNCTIONAL DIAGRAM



74LV574

LOGIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS^{1, 2}

In accordance with the Absolute Maximum Rating System (IEC 134) Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +7.0	V
±I _{IK}	DC input diode current	$V_{\rm I} < -0.5 \text{ or } V_{\rm I} > V_{\rm CC} + 0.5 V$	20	mA
±Іок	DC output diode current	$V_{\rm O}$ < -0.5 or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5V	50	mA
±IO	DC output source or sink current – bus driver outputs	35	mA	
±I _{GND} , ±I _{CC}	DC V _{CC} or GND current for types with -bus driver outputs		70	mA
T _{stg}	Storage temperature range		-65 to +150	°C
Ртот	Power dissipation per package –plastic DIL –plastic mini-pack (SO) –plastic shrink mini-pack (SSOP and TSSOP)	for temperature range: -40 to +125°C above +70°C derate linearly with 12mW/K above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	750 500 400	mW

NOTES:

 Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{CC}	DC supply voltage	See Note ¹	1.0	3.3	5.5	V
VI	Input voltage		0	-	V _{CC}	V
Vo	Output voltage		0	-	V _{CC}	V
T _{amb}	Operating ambient temperature range in free air	See DC and AC characteristics	-40 -40		+85 +125	°C
t _r , t _f	Input rise and fall times	$\begin{array}{c} V_{CC} = 1.0V \text{ to } 2.0V \\ V_{CC} = 2.0V \text{ to } 2.7V \\ V_{CC} = 2.7V \text{ to } 3.6V \\ V_{CC} = 3.6V \text{ to } 5.5V \end{array}$	- - - -		500 200 100 50	ns/V

NOTES:

1. The LV is guaranteed to function down to V_{CC} = 1.0V (input levels GND or V_{CC}); DC characteristics are guaranteed from V_{CC} = 1.2V to V_{CC} = 5.5V.

DC CHARACTERISTICS FOR THE LV FAMILY

Over recommended operating conditions voltages are referenced to GND (ground = 0V)

					LIMITS			
SYMBOL	PARAMETER	TEST CONDITIONS	-40)°C to +8	5°C	-40°C to	o +125°C	
			MIN	TYP ¹	MAX	MIN	MAX	1
		$V_{CC} = 1.2V$	0.9			0.9		
VIH	HIGH level Input	$V_{CC} = 2.0 V$	1.4			1.4] _v
ЧН	voltage	V _{CC} = 2.7 to 3.6V	2.0			2.0] `
		V _{CC} = 4.5 to 5.5V	0.7*V _{CC}			0.7*V _{CC}		
		$V_{CC} = 1.2V$			0.3		0.3	
VIL	LOW level Input	$V_{CC} = 2.0V$			0.6		0.6	
٩Ľ	voltage	V _{CC} = 2.7 to 3.6V			0.8		0.8	ľ
		V _{CC} = 4.5 to 5.5			0.3*V _{CC}		0.3*V _{CC}	
		$V_{CC} = 1.2V; V_I = V_{IH} \text{ or } V_{IL;} - I_O = 100 \mu A$		1.2				
		$V_{CC} = 2.0V; V_I = V_{IH} \text{ or } V_{IL;} - I_O = 100 \mu A$	1.8	2.0		1.8		
	HIGH level output voltage; all outputs HIGH level output voltage; BUS driver	$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL;} - I_O = 100 \mu A$	2.5	2.7		2.5		v
V _{OH}		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} - I_O = 100 \mu A$	2.8	3.0		2.8		
011		$V_{CC} = 4.5$ V; $V_I = V_{IH}$ or V_{IL} ; $-I_O = 100\mu$ A	4.3	4.5		4.3		
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} - I_O = 8mA$	2.40	2.82		2.20		
	outputs	$V_{CC} = 4.5V; V_I = V_{IH} \text{ or } V_{IL;} - I_O = 16 \text{mA}$	3.60	4.20		3.50		1
		$V_{CC} = 1.2V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$		0				
		$V_{CC} = 2.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$		0	0.2		0.2	1
	LOW level output voltage; all outputs	$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$		0	0.2		0.2	1
V _{OL}	vonage, an outputs	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$		0	0.2		0.2	
♥ OL		$V_{CC} = 4.5 V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$		0	0.2		0.2	1
	LOW level output	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 8mA$		0.20	0.40		0.50	1
	voltage; BUS driver outputs	$V_{CC} = 4.5 \text{V}; \text{V}_{\text{I}} = \text{V}_{\text{IH}} \text{ or } \text{V}_{\text{IL};} \text{I}_{\text{O}} = 16 \text{mA}$		0.35	0.55		0.65	1
I	Input leakage current	$V_{CC} = 5.5V; V_I = V_{CC} \text{ or GND}$			1.0		1.0	μA
I _{OZ}	3-State output OFF-state current	$V_{CC} = 5.5$ V; $V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND			5		10	μA
I _{CC}	Quiescent supply current; MSI	$V_{CC} = 5.5V; V_I = V_{CC} \text{ or GND}; I_O = 0$			20.0		160	μA
ΔI_{CC}	Additional quiescent supply current per input	$V_{CC} = 2.7V$ to 3.6V; $V_{I} = V_{CC} - 0.6V$			500		850	μA

NOTE:

1. All typical values are measured at T_{amb} = 25°C.

74LV574

74LV574

AC CHARACTERISTICS

 $GND = 0V; \ t_r = t_f \leq 2.5 ns; \ C_L = 50 pF; \ R_L = 1 K \Omega$

SYMBOL	PARAMETER	WAVEFORM	CONDITION		LIMITS 40 to +85	°C		IITS +125 ℃	UNIT	
			V _{CC} (V)	MIN	TYP	MAX	MIN	MAX		
			1.2	-	80	-	-	-		
			2.0	-	27	34	-	43		
t _{PHL} /t _{PLH}	Propagation delay CP to Qn	Figure 1, 4	2.7	-	20	25	-	31	ns	
			3.0 to 3.6	-	15 ²	20	-	25		
			4.5 to 5.5	-	-	17	-	21		
			1.2	-	70	-	-	-		
	3-State output		2.0	-	24	34	-	43		
t _{PZH} /t _{PZL}	enable time	Figure 2, 4	2.7	-	18	25	-	31	ns	
OE to Qn		3.0 to 3.6	-	13 ²	20	-	25			
		4.5 to 5.5	-	-	17	-	21			
3-State output		1.2	-	75	- 1	-	-			
		2.0	-	27	27	-	34			
t _{PHZ} /t _{PLZ}	t _{PHZ} /t _{PLZ} disable time	Figure 2, 4	2.7	-	21	21	-	26	ns	
	OE to Qn		3.0 to 3.6	-	16 ²	17	-	21		
			4.5 to 5.5	-	-	15	-	18		
			2.0	34	9	-	41	-	ns	
t _W	Clock pulse width HIGH or LOW	Figure 1	2.7	25	6	-	30	-		
			3.0 to 3.6	20	5 ²	- 1	24	-		
			1.2	-	10	-	-	-		
	Set-up time		2.0	22	4	-	26	-	20	
t _{su}	Dn to CP	Figure 3	2.7	16	3	- 1	19	-	ns	
			3.0 to 3.6	13	2 ²	-	15	-		
			1.2	-	-10	-	-	-		
	Hold time		2.0	5	-4	- 1	5	-	20	
t _h	Dn to CP	Figure 3	2.7	5	-3	- 1	5	-	ns	
			3.0 to 3.6	5	-2 ²	- 1	5	-		
			2.0	15	40	-	12	-		
f _{max}	Maximum clock pulse frequency	Figure 1	2.7	19	58	-	16	-	MHz	
			3.0 to 3.6	24	70 ²	- 1	20	-		

NOTE:

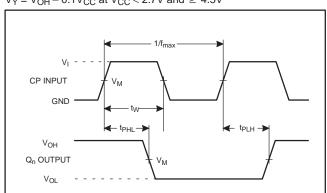
1. Unless otherwise stated, all typical values are at $T_{amb} = 25^{\circ}C$. 2. Typical value measured at $V_{CC} = 3.3V$.

74LV574

AC WAVEFORMS

 V_M = 1.5V at $V_{CC} \ge 2.7V$ and $\le 3.6V$ V_M = 0.5 * V_{CC} at $V_{CC} < 2.7V$ and $\ge 4.5V$ V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load. V_X = V_{OL} + 0.3V at $V_{CC} \ge 2.7V$ and $\le 3.6V$

 $\begin{array}{l} V_X = V_{OL} + 0.1 V_{CC} \text{ at } V_{CC} < 2.7 V \text{ and } \geq 4.5 V \\ V_Y = V_{OH} - 0.3 V \text{ at } V_{CC} \geq 2.7 V \text{ and } \leq 3.6 V \\ V_Y = V_{OH} - 0.1 V_{CC} \text{ at } V_{CC} < 2.7 V \text{ and } \geq 4.5 V \end{array}$



SV00718

Figure 1. Clock (CP) to output (Qn) propagation delays, the clock pulse (CP) and the maximum clock pulse frequency

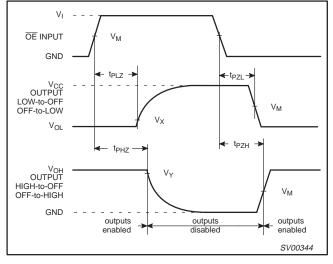


Figure 2. 3-state enable and disable times

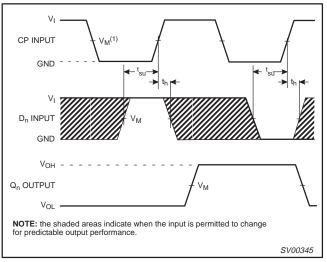
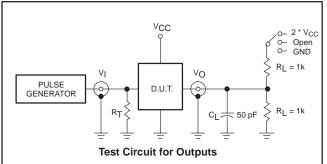


Figure 3. Data set-up and hold times for the Dn input to the CP input

NOTE:

The shaded areas indicate when the input is permitted to change for predictable output performance.

TEST CIRCUIT



DEFINITIONS

R_L = Load resistor

 C_{L} = Load capacitance includes jig and probe capacitiance.

 R_T = Termination resistance should be equal to Z_{OUT} of pulse generators.

SWITCH POSITION

TEST	S ₁		V _{CC}	vı
t _{PLH} /t _{PHL}	Open		< 2.7V	V _{CC}
t _{PLZ} /t _{PZL}	2 * V _{CC}		2.7–3.6V	2.7V
t _{PHZ} /t _{PZH}	GND	1	≥ 4.5V	V _{CC}

SV00896

Figure 4. Load circuitry for switching times

DIP20: plastic dual in-line package; 20 leads (300 mil)



Octal D-type flip-flop; positive edge-trigger (3-State)





seating plane

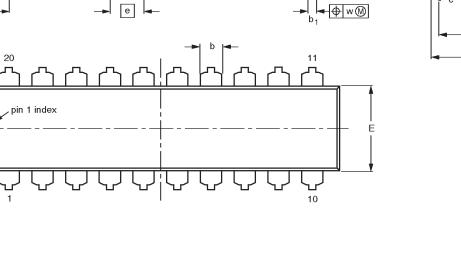


 M_{E}

Ш

M_H

A'1





DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	с	D ⁽¹⁾	Е ⁽¹⁾	e	e ₁	L	M _E	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	0.36 0.23	26.92 26.54	6.40 6.22	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.0
inches	0.17	0.020	0.13	0.068 0.051	0.021 0.015	0.014 0.009	1.060 1.045	0.25 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.078

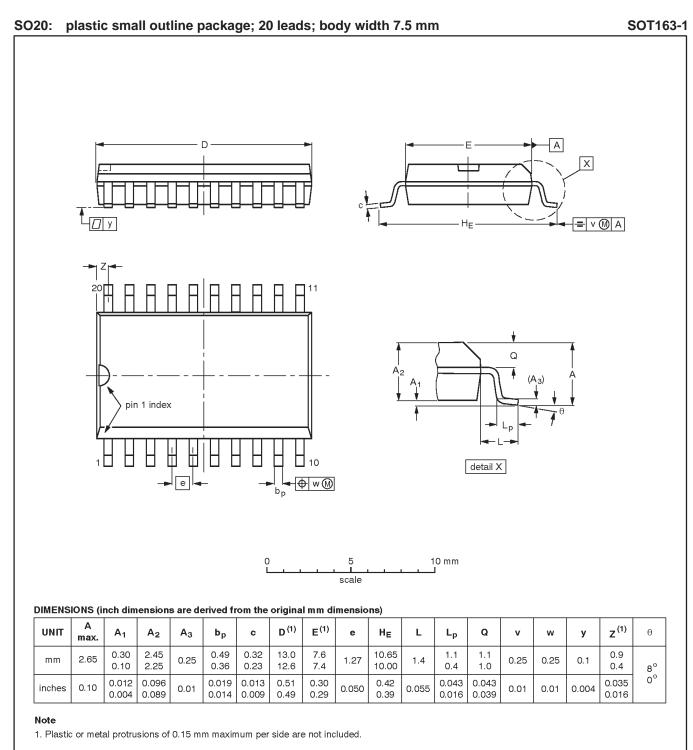
Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	
SOT146-1			SC603		-92-11-17 95-05-24	

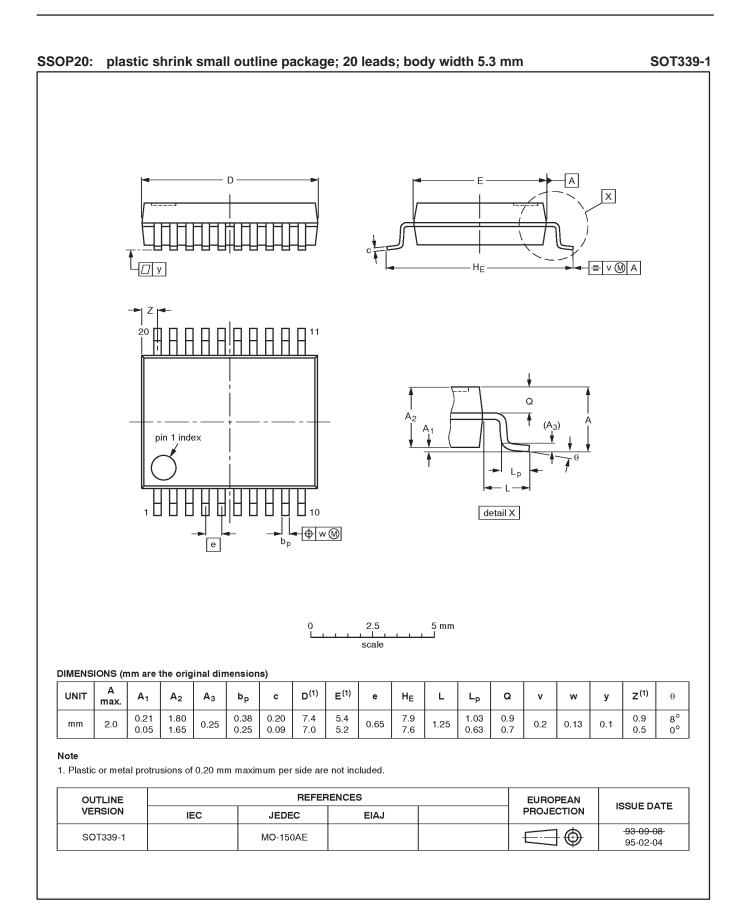
Product specification

74LV574



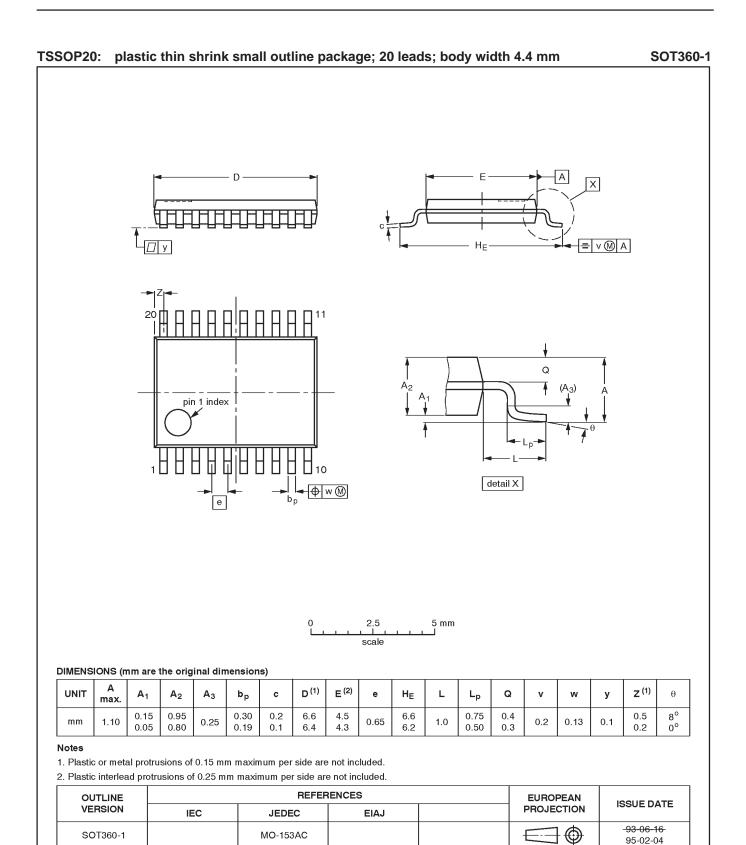
OUTLINE		REFER	ENCES		EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT163-1	075E04	MS-013AC				-92-11-17 95-01-24	

74LV574



10

74LV574



74LV574

DEFINITIONS		
Data Sheet Identification	Product Status	Definition
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.
Preliminary Specification	Preproduction Product	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
Product Specification	Full Production	This data sheet contains Final Specifications. Philips Semiconductors reserves the right to make changes at any time without notice, in order to improve design and supply the best possible product.

Philips Semiconductors and Philips Electronics North America Corporation reserve the right to make changes, without notice, in the products, including circuits, standard cells, and/or software, described or contained herein in order to improve design and/or performance. Philips Semiconductors assumes no responsibility or liability for the use of any of these products, conveys no license or title under any patent, copyright, or mask work right to these products, and makes no representations or warranties that these products are free from patent, copyright, or mask work right infringement, unless otherwise specified. Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

LIFE SUPPORT APPLICATIONS

Philips Semiconductors and Philips Electronics North America Corporation Products are not designed for use in life support appliances, devices, or systems where malfunction of a Philips Semiconductors and Philips Electronics North America Corporation Product can reasonably be expected to result in a personal injury. Philips Semiconductors and Philips Electronics North America Corporation customers using or selling Philips Semiconductors and Philips Electronics North America Corporation Products for use in such applications do so at their own risk and agree to fully indemnify Philips Semiconductors and Philips Electronics North America Corporation for any damages resulting from such improper use or sale.

Philips Semiconductors 811 East Arques Avenue P.O. Box 3409 Sunnyvale, California 94088–3409 Telephone 800-234-7381 © Copyright Philips Electronics North America Corporation 1998 All rights reserved. Printed in U.S.A.

print code

Document order number:

Date of release: 05-96 9397-750-04454

Let's make things better.



PHILIPS

Semiconductors

Philips